

PMLL4148L; PMLL4448

High-speed switching diodes

Rev. 07 — 31 January 2007

Product data sheet

1. Product profile

1.1 General description

Single high-speed switching diodes, fabricated in planar technology, and encapsulated in small hermetically sealed glass SOD80C Surface-Mounted Device (SMD) packages.

Table 1. Product overview

Type number	Package	Configuration
PMLL4148L	SOD80C	single
PMLL4448		

1.2 Features

- High switching speed: $t_{rr} \leq 4 \text{ ns}$
- Reverse voltage: $V_R \leq 75 \text{ V}$
- Repetitive peak reverse voltage: $V_{RRM} \leq 100 \text{ V}$
- Repetitive peak forward current: $I_{FRM} \leq 450 \text{ mA}$
- Small hermetically sealed glass SMD package

1.3 Applications

- High-speed switching
- Reverse polarity protection

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_F	forward current	[1]	-	-	200	mA
I_{FRM}	repetitive peak forward current		-	-	450	mA
V_R	reverse voltage		-	-	75	V

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	100	V
V_R	reverse voltage		-	75	V
I_F	forward current	[1]	-	200	mA
I_{FRM}	repetitive peak forward current		-	450	mA
I_{FSM}	non-repetitive peak forward current	square wave $t_p = 1 \mu s$ $t_p = 1 ms$ $t_p = 1 s$	[2] - - -	4 1 0.5	A
P_{tot}	total power dissipation	$T_{amb} = 25^\circ C$	[1]	500	mW
T_j	junction temperature		-	200	$^\circ C$
T_{amb}	ambient temperature		-65	+200	$^\circ C$
T_{stg}	storage temperature		-65	+200	$^\circ C$

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] $T_j = 25^\circ C$ prior to surge.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	-	K/W

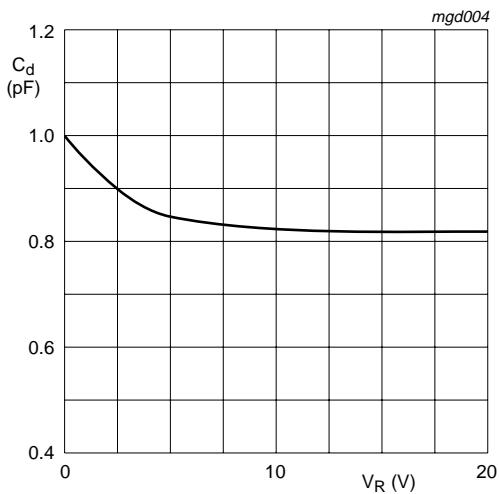
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 8. Characteristics $T_{amb} = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
V_F	forward voltage						
	PMLL4148L	$I_F = 50 \text{ mA}$	-	-	1	V	
	PMLL4448	$I_F = 5 \text{ mA}$	620	-	720	mV	
		$I_F = 100 \text{ mA}$	-	-	1	V	
I_R	reverse current	$V_R = 20 \text{ V}$	-	-	25	nA	
		$V_R = 20 \text{ V}; T_j = 150^\circ\text{C}$	-	-	50	μA	
I_R	reverse current	$V_R = 20 \text{ V}; T_j = 100^\circ\text{C}$	-	-	3	μA	
C_d	diode capacitance	$V_R = 0 \text{ V}; f = 1 \text{ MHz}$	-	-	4	pF	
t_{rr}	reverse recovery time		[1]	-	-	4	ns
V_{FR}	forward recovery voltage		[2]	-	-	2.5	V

[1] When switched from $I_F = 10 \text{ mA}$ to $I_R = 60 \text{ mA}$; $R_L = 100 \Omega$; measured at $I_R = 1 \text{ mA}$.[2] When switched from $I_F = 50 \text{ mA}$; $t_r = 20 \text{ ns}$.



$f = 1 \text{ MHz}; T_j = 25 \text{ }^{\circ}\text{C}$

Fig 5. Diode capacitance as a function of reverse voltage; typical values

8. Test information

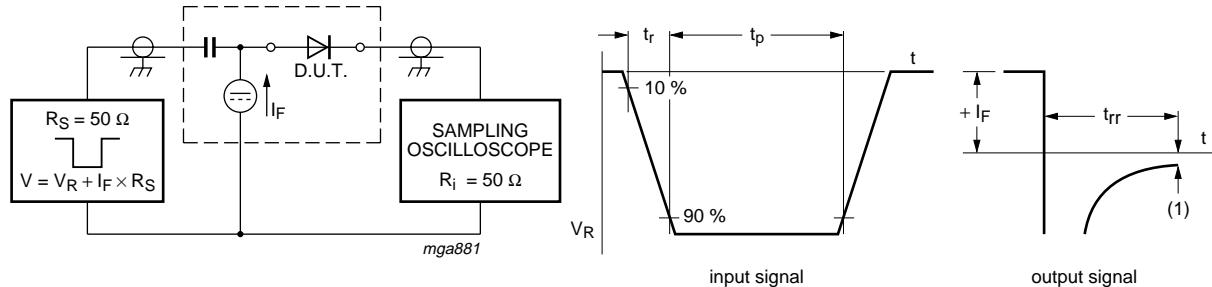


Fig 6. Reverse recovery time test circuit and waveforms

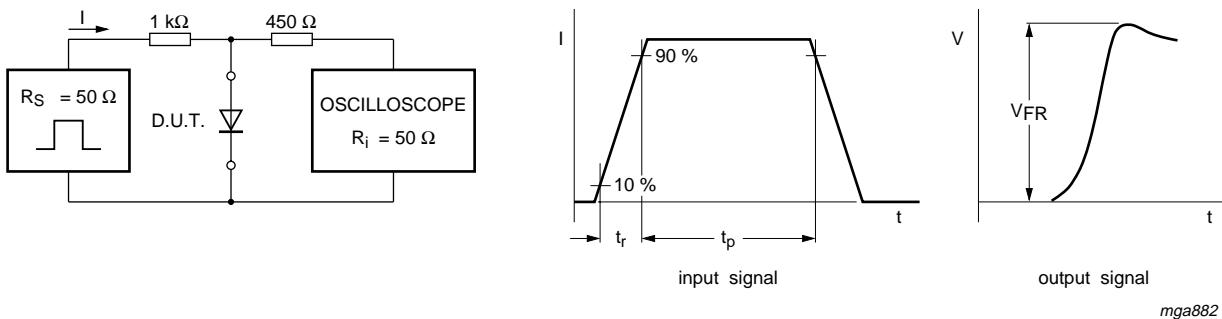


Fig 7. Forward recovery voltage test circuit and waveforms

9. Package outline

Hermetically sealed glass surface-mounted package; 2 connectors

SOD80C

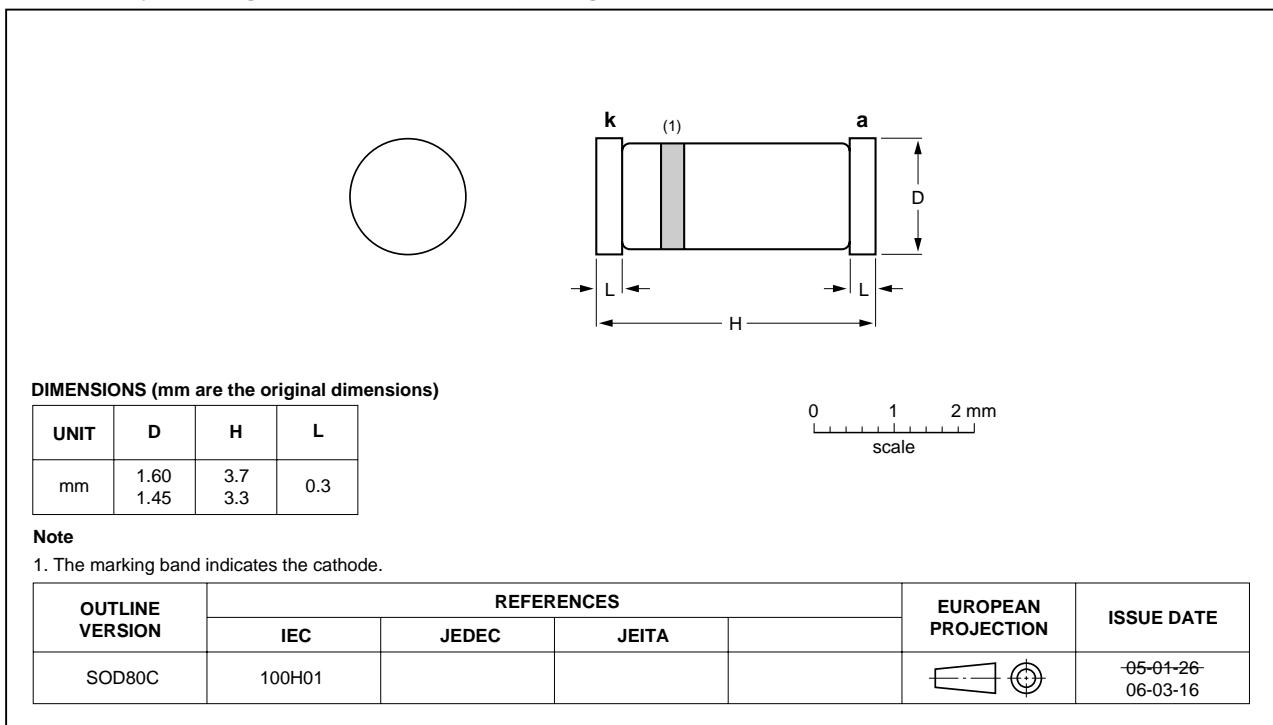


Fig 8. Package outline SOD80C

10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

Type number	Package	Description	Packing quantity	
			2500	10000
PMLL4148L	SOD80C	4 mm pitch, 8 mm tape and reel	-115	-135
PMLL4448				

[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering

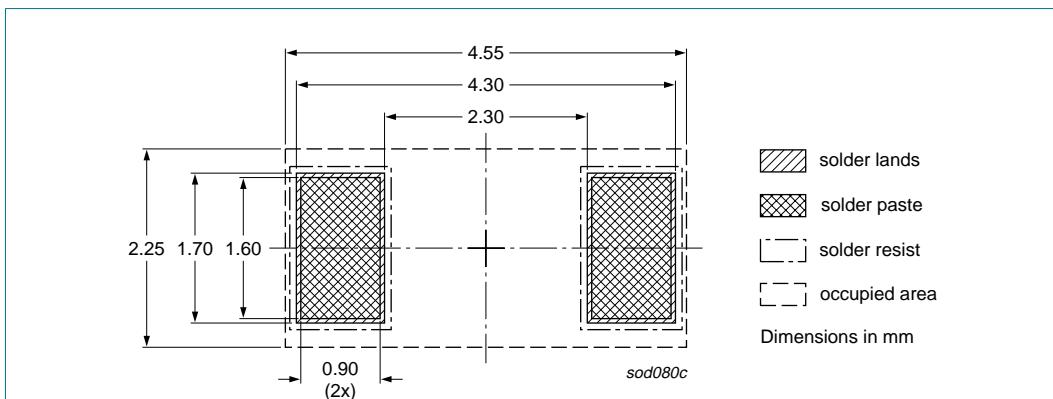


Fig 9. Reflow soldering footprint SOD80C

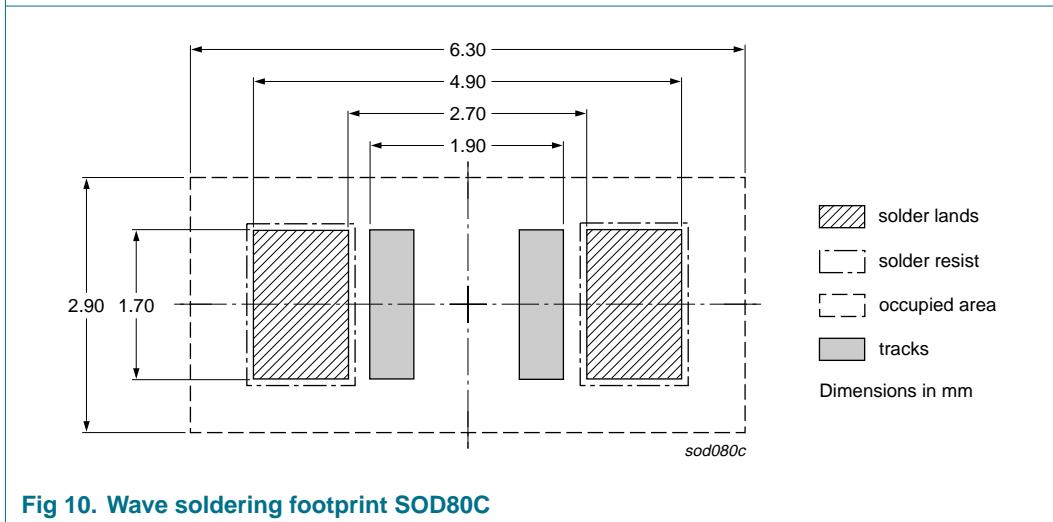


Fig 10. Wave soldering footprint SOD80C

12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMLL4148L_PMLL4448_7	20070131	Product data sheet	-	PMLL4148L_PMLL4448_6
Modifications:		<ul style="list-style-type: none"> • The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. • Legal texts have been adapted to the new company name where appropriate. • <u>Section 1.2 "Features"</u>: adapted • <u>Section 1.3 "Applications"</u>: amended • <u>Table 2 "Quick reference data"</u>: V_F conditions for PMLL4148L updated • <u>Table 8 "Characteristics"</u>: V_F conditions for PMLL4148L updated • <u>Figure 4</u>: unit for I_R in axis description amended to μA • <u>Section 13 "Legal information"</u>: updated 		
PMLL4148L_PMLL4448_6	20050404	Product data sheet	-	PMLL4148L_4448_5
PMLL4148L_4448_5	20020123	Product specification	-	PMLL4148L_4448_4
PMLL4148L_4448_4	20001115	Product specification	-	PMLL4148_3
PMLL4148_3	19990527	Product specification	-	PMLL4148_2
PMLL4148_2	19960918	Product specification	-	PMLL4148_1
PMLL4148_1	19960423	Product specification	-	-

15. Contents

1	Product profile	1
1.1	General description	1
1.2	Features	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Marking	2
5	Limiting values	3
6	Thermal characteristics	3
7	Characteristics	4
8	Test information	6
9	Package outline	7
10	Packing information	7
11	Soldering	8
12	Revision history	9
13	Legal information	10
13.1	Data sheet status	10
13.2	Definitions	10
13.3	Disclaimers	10
13.4	Trademarks	10
14	Contact information	10
15	Contents	11

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

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Date of release: 31 January 2007

Document identifier: PMLL4148L_PMLL4448_7